

Features

- 650-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_E

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

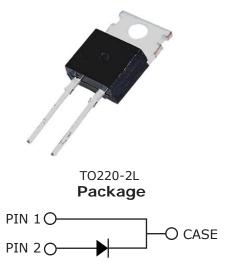
Applications

- Switch Mode Power Supplies
- Power Factor Correction
- Motor Drives



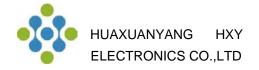


Part Number	Package	Marking
HC3D20065A	TO220-2L	HC3D20065A



Maximum Ratings ($T_c = 25$ °C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions
$V_{_{\mathrm{RRM}}}$	Repetitive Peak Reverse Voltage	650	٧	
V _{RSM}	Surge Peak Reverse Voltage	650	V	
V _{DC}	DC Blocking Voltage	650	V	
I _F	Continuous Forward Current	20	А	T _c =125°C
I _{FRM}	Repetitive Peak Forward Surge Current	81	Α	T _c =110°C, t _p =10 ms, Half Sine Wave
I _{FSM}	Non-Repetitive Peak Forward Surge Current	123 104	Α	T_c =25°C, t_p = 10 ms, Half Sine Wave T_c =150°C, t_p = 10 ms, Half Sine Wave
I _{F,Max}	Non-Repetitive Peak Forward Surge Current	450	Α	T_c =25°C, t_p = 10 μ s, Pulse
P _{tot}	Power Dissipation	115	W	T _c =25°C
T_{J} , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°C	



Electrical Characteristics

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions
V _F	Forward Voltage	1.35 1.5	1.5 -	٧	I _F = 20 A ,T _J =25°C I _F = 20 A ,T _J =175°C
I _R	Reverse Current	0.06 12	100 -	μА	V _R = 650 V T _J =25°C V _R = 650 V T _J =175°C
Q _c	Total Capacitive Charge	24		nC	$V_R = 400 \text{ V, } I_F = 10 \text{ A}$ di/dt = 500 A/\mus $T_J = 25^{\circ}\text{C}$
С	Total Capacitance	1000 91		pF	V _R = 0 V, T _J = 25°C, f = 1 MHz V _R = 400 V, T _J = 25°C, f = 1 MHz
E _{ava}	Non-repetetive Avaranche Energy	220		mJ	L=1mH

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
R _{eJC}	Thermal Resistance from Junction to Case	0.87	°C/W

Typical Performance

Fig.1 V_F - I_F Characteristics

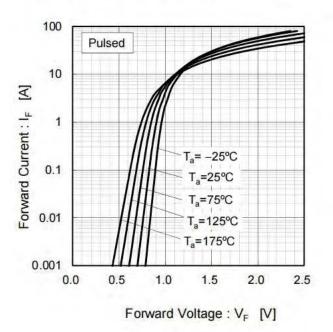
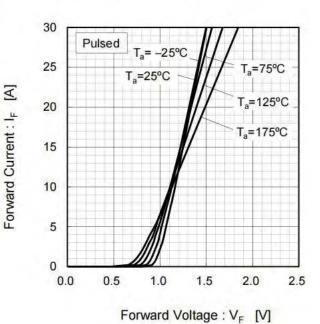
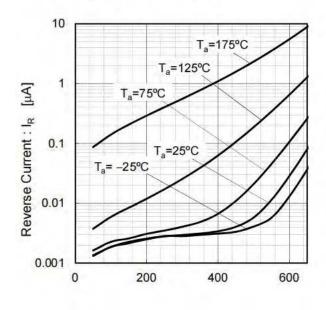


Fig. 2 V_F - I_F Characteristics



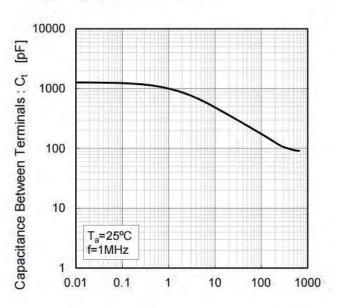
Typical Performance

Fig. 3 V_R - I_R Characteristics



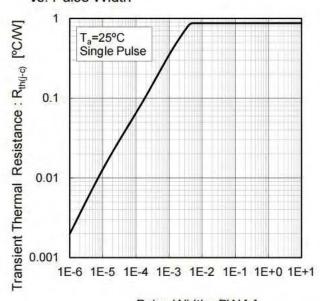
Reverse Voltage : V_R [V]

Fig.4 V_R-C_t Characteristics



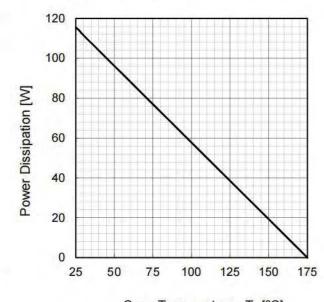
Reverse Voltage : V_R [V]

Fig.5 Typical Transient Thermal Resistance vs. Pulse Width



Pulse Width: PW [s]

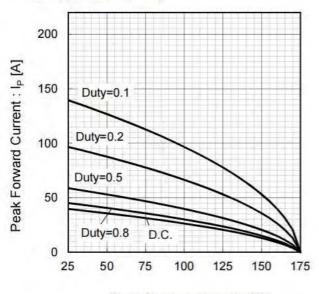
Fig.6 Power Dissipation



Case Temperature : T_c [°C]

Typical Performance

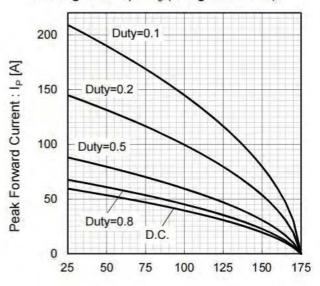
Fig.7*3 Maximum peak forward current derating curve $I_P - T_c$



Case Temperature : T_c [°C]

 $^{\star}3$ Based on max Vf, max R_{th(j-c)} Valid for switching of above 10kHz, excluding D.C. curve.

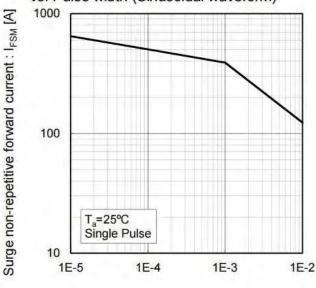
Fig.8*4 Typical peak forward current derating curve I_P - T_c (Not guaranteed)



Case Temperature : T_c [°C]

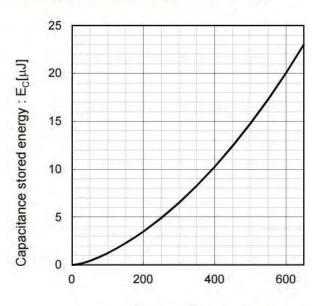
*4 Based on typ Vf, typ R_{th(j-c)} Typical value, not guaranteed Valid for switching of above 10kHz, excluding D.C. curve

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

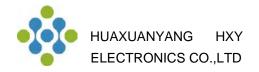


Pulse Width: PW[s]

Fig. 10 Typical capacitance store energy



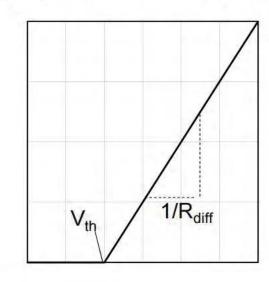
Reverse Voltage : V_R [V]



Typical Performance

Forward Current : I_F

Fig.11 Equivalent forward current curve



Forward Voltage: V_F

$$V_F = V_{th} + R_{diff} I_F$$

$$V_{th}(T_j) = a_0 + a_1 T_j$$

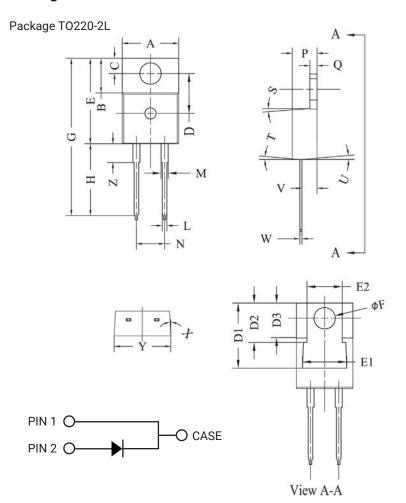
 $R_{diff}(T_j) = b_0 + b_1 T_j + b_2 T_j^2$

Symbol	Typical Value	Unit	
a_0	9.66E-01	V	
a ₁	- 1.10E-03	V/°C	
b ₀	1.76E-02	Ω	
b ₁	3.73E-05	Ω/°C	
b ₂	3.84E-07	$\Omega / ^{\circ}C^{2}$	

 T_j in °C; -55 °C < T_j < 175°C ; I_F < 40A



Package Dimensions

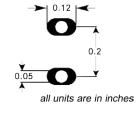


	Inc	hes	Millimeters		
POS	Min	Max	Min	Max	
А	.381	.410	9.677	10.414	
В	.235	.255	5.969	6.477	
С	.100	.120	2.540	3.048	
D	.223	.337	5.664	8.560	
D1	.457490		11.60-12.45 typ		
D2	.2773	303 typ	7.04-7.70 typ		
D3	.2442	252 typ	6.22-6	5.4 typ	
E	.590	.615	14.986	15.621	
E1	.302	.326	7.68	8.28	
E2	.227	251	5.77	6.37	
F	.143	.153	3.632	3.886	
G	1.105	1.147	28.067	29.134	
Н	.500	.550	12.700	13.970	
L	.025	.036	.635	.914	
М	.045	.055	1.143	1.550	
N	.195	.205	4.953	5.207	
Р	.165	.185	4.191	4.699	
Q	.048	.054	1.219	1.372	
S	3°	6°	3°	6°	
Т	3°	6°	3°	6°	
U	3°	6°	3°	6°	
V	.094	.110	2.388	2.794	
W	.014	.025	.356	.635	
Х	3°	5.5°	3°	5.5°	
Υ	.385	.410	9.779	10.414	
Z	.130	.150	3.302	3.810	

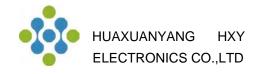
NOTE:

1. Dimension L, M, W apply for Solder Dip Finish

Recommended Solder Pad Layout



T0220-2L



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